ON Semiconductor

Is Now

Onsemi

To learn more about onsemi[™], please visit our website at <u>www.onsemi.com</u>

onsemi and ONSEMI. and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product factures, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and asfety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or by customer's technical experts. onsemi products and actal performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use onsemi products for any such unintended or unauthorized application, Buyer shall indemnify and hold onsemi and its officers, employees, subsidiari



FSUSB63 — 3:1 High-Speed USB 2.0 Switch / Multiplexer

Features

Sw itch Type	3:1 USB Switch
USB	USB 2.0 High-Speed &
036	Full-Speed Compliant
Break-Before-Make Time	126µs
R _{ON}	6Ω Typical
CON	6pF Typical
Bandw idth	830MHz
Vcc	2.7 to 4.4V
V _{CNTRL}	0 to V _{CC}
Operating Temperature	-40°C to 85°C
ICCSLP	<1µA
ICCACT	7.5µA Typical
Package	12- Lead UMLP 1.80 x 1.80 x
Fachage	0.55mm, 0.40mm pitch
Top Mark	KG
Ordering Information	FSUSB63UMX

Applications

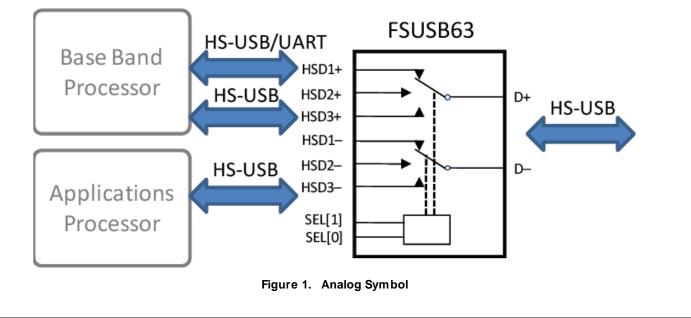
- Cell Phone, Digital Camera, Notebook
- LCD Monitor, TV, and Set-Top Box
- Netbook, Mobile Internet Device (MID)

Description

The FSUSB63 is a bi-directional, low -pow er, High-Speed (HS) USB 2.0 3:1 Multiplexer (MUX). It is optimized for switching among three high-speed (480Mbps) sources or any combination of high-speed and full-speed (12Mbps) USB sources, such as an application processor, to one USB 2.0 connector.

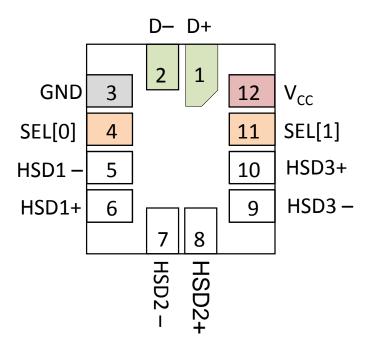
The FSUSB63 has a break-before-make time to force reenumeration by the host when switching between different HS USB 2.0 controllers and thus requires minimal software changes.

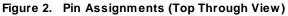
The FSUSB63 is compliant with the requirements of USB 2.0 and features extremely low on capacitance (C_{ON}). The wide bandwidth exceeds the requirement to pass the third harmonic, resulting in signals with minimum edge and phase distortion. Superior channel-to-channel crosstalk also minimizes interference.



Typical Application

Pin Configuration





Pin Descriptions

Pin #	Name	Description	
1	D+	USB 2.0 High Speed or Full Speed Data BusD+	
2	D-	USB 2.0 High Speed or Full Speed Data BusD-	
3	GND	Ground	
4	SEL[0]	Path Selection Control Inputs (see functional table below)	
5	HSD1-	Multiplexed First Source Path for D-	
6	HSD1+	Multiplexed First Source Path for D+	
7	HSD2-	ultiplexed Second Source Path for D-	
8	HSD2+	Multiplexed Second Source Path for D+	
9	HSD3-	Multiplexed Third Source Path for D-	
10	HSD3+	Multiplexed Third Source Path for D+	
11	SEL[1]	Path Selection Control Inputs (see functional table below)	
12	V _{cc}	Supply Voltage	

Functional Table

Mode	SEL[1]	SEL[0]	Function
Sleep Mode	0	0	D+, D- Switch PathsOpen
USB Port 1	0	1	D+=HSD1+, D-=HSD1-
USB Port 2	1	0	D+=HSD2+, D-=HSD2-
USB Port 3	1	1	D+=HSD3+, D-=HSD3-

Eye Compliance 0.5 0.4 0.3 0.2 0.1 rential Signal, V Diffe -0.2 -0.3 -0.4 -0.5 2.0 0.0 0.2 0.6 1.2 1.4 1.6 1.8 0.4 0.8 1.0 Time (x10^-9)s

Figure 3. USB 2.0 HS-USB Eye Compliance Pass Through (without Switch)

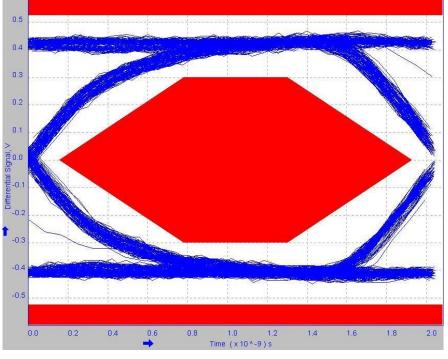


Figure 4. USB 2.0 HS-USB Eye Compliance with Switch

Notes:

- 1. Figure 3 indicates the HS-USB eye compliance of the source across a characterization board proir to the implementation of the sw tich.
- 2. Figure 4 shows the total impact the swich has on HS-USB eye compliance when compared to Figure 3

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Min.	Max.	Unit	
Vcc	Supply Voltage	-0.50	5.25	V	
V _{CNTRL}	DC Input Voltage (SEL[1:0]) ⁽³⁾		-0.5	V _{CC}	V
V _{SW}	DC Switch I/O Voltage ⁽³⁾		-0.50	5.25	V
lıк	DC Input Diode Current		-50		mA
Юυт	DC Switch Current			50	mA
T _{STG}	Storage Temperature	-65	+150	°C	
MSL	Moisture Sensitivity Level (JEDEC J-STD-020A)		1	Level	
	IEC61000-4-2 System on USB Connector Pins		15.0		
	D+ & D-	Contact	8.0		
ESD	ESD		16.0		kV
LOD	Human Body Model, JEDEC: JESD22-A114	VO to GND	5.0		Ň
		All Pins	5.0		
	Charged Device Model, JEDEC: JESD22-C101		1.5		

Note:

3. The input and output negative ratings may be exceeded if the input and output diode current ratings are observed.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. ON Semiconductor does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Max.	Unit
V _{CC}	Supply Voltage	2.7	4.4	V
Vcntrl ⁽⁴⁾	Control Input Voltage (SEL[1:0])	0	Vcc	V
V _{SW}	Switch I/O Voltage	-0.5	4.3	V
T _A	Operating Temperature	-40	+85	°C

Note:

4. The control input must be held HIGH or LOW and it must not float.

DC Electrical Characteristics

All typical values are for V_CC=3.3V at T_A=25°C unless otherwise specified.

Sumbel	Perameter	Conditions		T _A =-	L ha it a		
Symbol	Parameter	Conditions	V _{CC} (V)	Min.	Тур.	Max.	Units
VIK	Clamp Diode Voltage	I _{IN} =-18mA	2.7			-1.2	V
VIH	Input Voltage High	SEL[1], SEL[0] Inputs	2.7 to 4.3	1.0			V
V _{IL}	Input Voltage Low	SEL[1], SEL[0] Inputs	2.7 to 4.3			0.35	V
I _{IN}	Control Input Leakage	All Combinations of SEL[1] & SEL[0] in the Truth Table (LOW=0V & HIGH=V $_{CC}$)	4.3			1	μA
l _{oz}	Off-State Leakage	$0 \leq D_n$, HSD1 _n , HSD2 _n , HSD3 _n $\leq 3.6V$	4.3	-2		2	μA
I _{OFF}	Power-Off Leakage Current (All I/O Ports)	V_{SW} =0V to 4.3V, V_{CC} =0V, Figure 7	0	-2		2	μA
R _{0N} ⁽⁵⁾	HS Switch On Resistance	V_{SW} =0.4V, I_{ON} =-8mA, Figure 6	3.0		6.0	7.8	Ω
ΔR_{ON}	HS Delta R _{on} ⁽⁶⁾	V _{SW} =0.4V, I _{ON} =-8mA	3.0		0.50		Ω
I _{CCSLP}	Sleep Mode Supply Current	SEL[1]=SEL[0]=0	3.6			1	μA
	Active Made Supply Current	V _{CNTRL} =0 or V _{CC} ,	2.7		7.5	15.0	μA
CCACT	Active Mode Supply Current	I _{OUT} =0	3.6		8.5	16.0	μA
	Increase in I_{CC} Current per Control Input	V _{CNTRL} =1.8V	3.6		1.5	4.0	μA
I _{CCT}	and V_{cc}	V _{CNTRL} =1.2V	3.6		3.0	5.0	μA

Notes:

5. Measured by the voltage drop betw een HSD_n and D_n pins at the indicated current through the switch.

On resistance is determined by the low er of the voltage on the two (HSD_n or D_n ports).

6. Guaranteed by characterization.

AC Electrical Characteristics

All typical values are for V_{CC} =3.3V at T_A=25°C unless otherwise specified.

Symbol	Parameter	Conditions		T _A =-	Units		
Symbol	Farameter	Conditions	ns V _{CC} (V)		Тур.	Max.	Units
t _{on}	Turn-On Time when Switching from One USB Path (or Disabled i.e. SEL=00) to Another USB Path	R _L =50Ω, C _L =35pF V _{sw} =0.8V Figure 8, Figure 9	3.0 to 3.6	126		400	μs
t _{OFF}	Turn-Off Time SEL≠00 (Any of the Three USB Paths Active) to SEL=00 (Disabled)	R _L =50Ω, C _L =35pF V _{sw} = 0.8V Figure 8, Figure 9	3.0 to 3.6			45	ns
t _{PD}	Propagation Delay ⁽⁷⁾	C∟=5pF, R∟=50Ω Figure 8, Figure 10	3.3		0.25		ns
t _{BBM}	Break-Before-Make Time	$\begin{array}{l} R_L = 50 \Omega, \ C_L = 35 p F \\ V_{SW1} = V_{SW2} = 0.8 V, \\ Figure \ 12 \end{array}$	3.0 to 3.6	126		400	μs
O _{IRR}	Off Isolation ⁽⁷⁾	R∟=50Ω, f=240MHz Figure 14	3.0 to 3.6		-42		dB
Xtalk	Non-Adjacent Channel Crosstalk ⁽⁷⁾	R∟=50Ω, f=240MHz Figure 15	3.0 to 3.6		-33		dB
BW	-3db Bandwidth ⁽⁷⁾	R∟=50Ω, C∟=0pF Figure 13	3.0 to 3.6		830		MHz
511		$R_L=50\Omega$, $C_L=5pF$ Figure 13	3.0 to 3.6		510		MHz

Note:

7. Guaranteed by characterization.

USB High-Speed Related AC Electrical Characteristics

Symbol	Symbol Parameter Conditions			TA=-	40ºC to	+85⁰C	Units		
Symbol	Farameter	Conditions	Vcc (V)		VCC (V)	Min.	Тур.	Max.	Units
t _{SK(P)}	Pulse Skew ⁽⁸⁾	V _{SW} =0.2Vdiff _{PP} , Figure 11, C _L =5pF	3.0 to 3.6		10		ps		
t _{SK(I)}	Skew Between Differential Signals within a Pair ⁽⁸⁾	V _{SW} =0.2Vdiff _{PP} , Figure 11, C _L =5pF	3.0 to 3.6		10		ps		

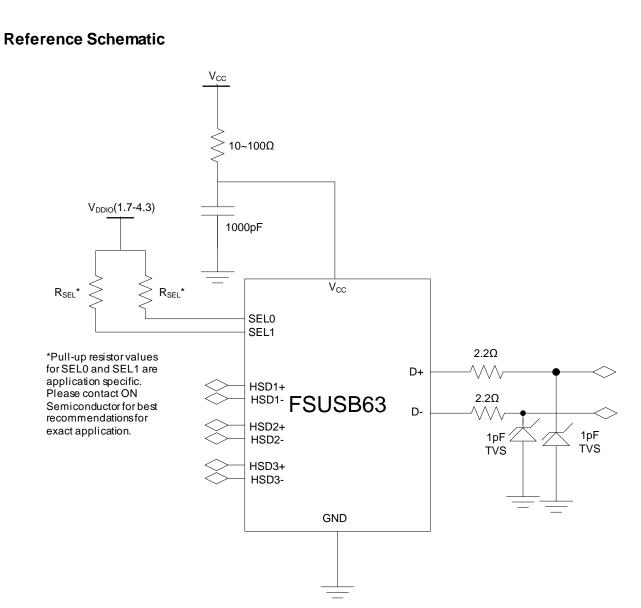
Capacitance

Symbol	Parameter	ter Conditions	T _A =- 40°C to +85°C			Units
Symbol	Falameter	Conditions	Min.	Тур.	Max.	Units
CiN	SEL[1:0] Input Capacitance ⁽⁸⁾	V _{CC} =0V		3		
Con	D+/D- On Capacitance ⁽⁸⁾	V _{CC} =3.3V, Any of the Three Switch Paths Enabled, f=1MHz, Figure 17		6		ъĘ
SON	on oupdoiding	V_{CC} =3.3V, Any of the Three Switch Paths Enabled, f=240MHz ⁽⁹⁾		5		pF
COFF	HSD1 _n , HSD2 _n , HSD3 _n Off Capacitance ⁸⁾	V _{CC} =0V or (V _{CC} =3.3V and SEL[1]=SEL[0]=0V) Figure 16		2		

Notes:

8. Guaranteed by characterization.

9. Effective capacitance measured on a network analyzer.





Test Diagrams

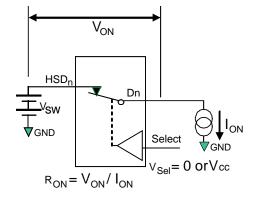
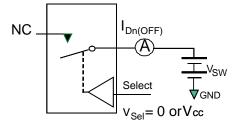
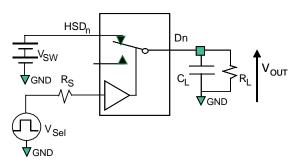


Figure 6. On Resistance



**Each switch port is tested separately

Figure 7. Off Leakage



 R_L , R_S , and C_L are functions of the application environment (see AC Tables for specific values) C_l includes test fixture and stray capacitance.



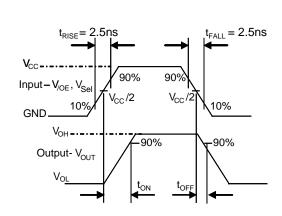
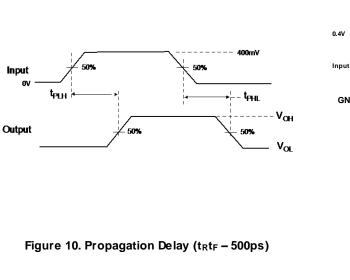
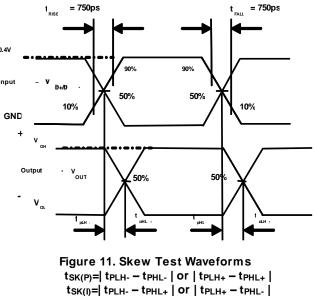
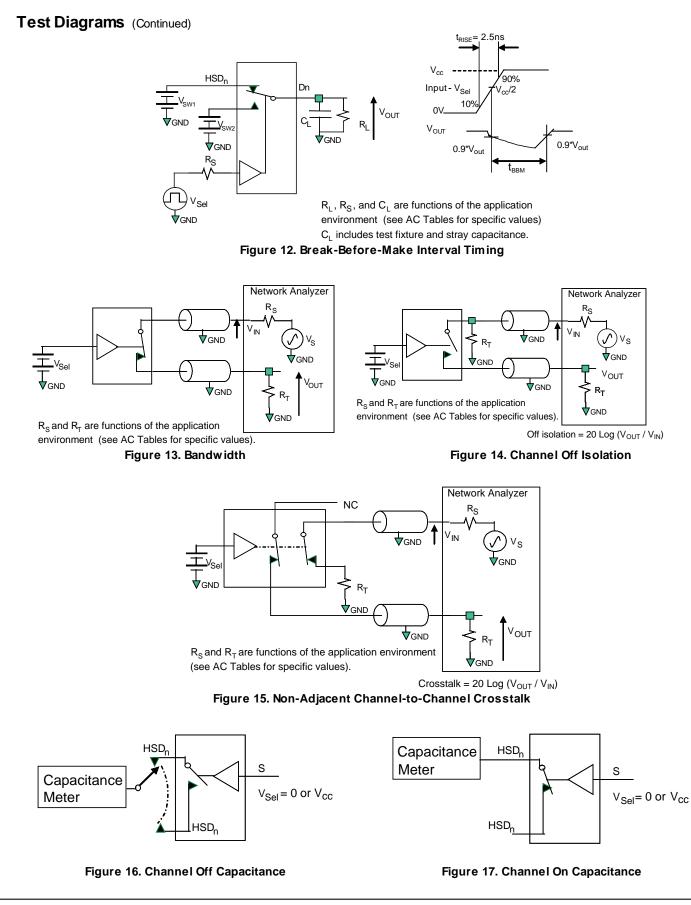


Figure 9. Turn-On / Turn-Off Waveforms







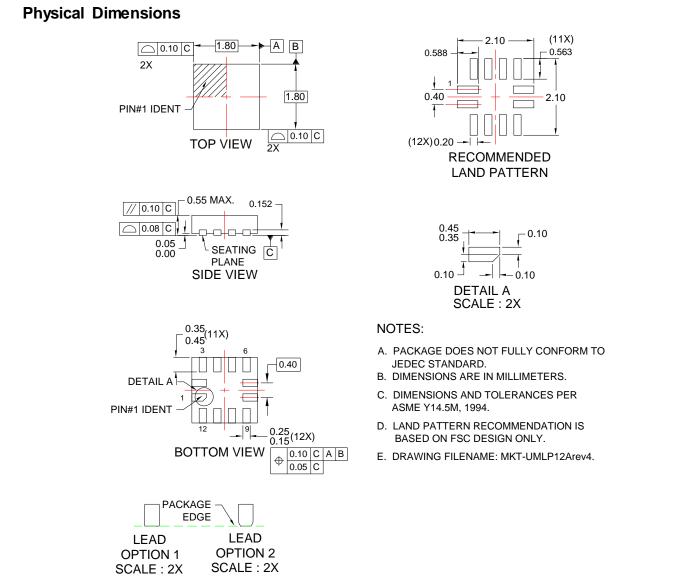


Figure 18. 12-Lead, Ultrathin Molded Leadless Package (UMLP)

Ordering Information

Part Number	Top Mark	Operating Temperature Range	Package
FSUSB63UMX	KG		12-Lead, Quad, Ultrathin Molded Leadless Package (UMLP), 1.8mm x 1.8mm x 0.55mm, 0.4mm pitch

Package drawings are provided as a service to customers considering ON Semiconductor components. Drawings may change in any manner without notice. Please note the revision and/or date on the drawing and contact a ON Semiconductor representative to verify or obtain the most recent revision. Package specifications do not expand the terms of ON Semiconductor's worldwide terms and conditions, specifically the warranty therein, which covers ON Semiconductor products.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and requirements standards, regardless of any support or applications information safety or provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax : 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800-282-9855 Toll Free USA/Canada.

Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81-3-5817-1050 ON Semic onductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Onsemi: FSUSB63UMX